

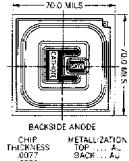
SCRs

1.6 Amp, Planar

2N2323-2N2329, J, JTX, JTXV
 2N2323A-2N2328A, J, JTX, JTXV
 2N2323S-2N2329S, J, JTX, JTXV
 2N2323AS-2N2328AS, J, JTX, JTXV

FEATURES

- Available as JAN, JANTX, & JANTXV Types
- JAN Types Available in TO-5
- 1.6A D.C. Current
- Peak Currents: to 30A
- Voltage Ratings: to 400V
- 20 μ A Max. Trigger Current ("A" types)
- 0.6V Max. Trigger Voltage ("A" types)



DESCRIPTION

These are premium thyristor switches intended for use in high performance industrial, military and space applications requiring a high degree of reliability assurance. This series is useful in a wide variety of applications including timing and programming circuits, protective and warning circuits, driving relays, driving indicator lamps, encoding and decoding circuits, replacing relays, thyratrons, and magamps, servo motor control, pulse generation, plus many others. The high surge current rating (15A - 1 cycle) makes this series particularly useful for squib firing.

The following JAN, JANTX and JANTXV types are specified under Mil-S-19500/276A and are included in Mil-STD-701 as recommended types for military usage:

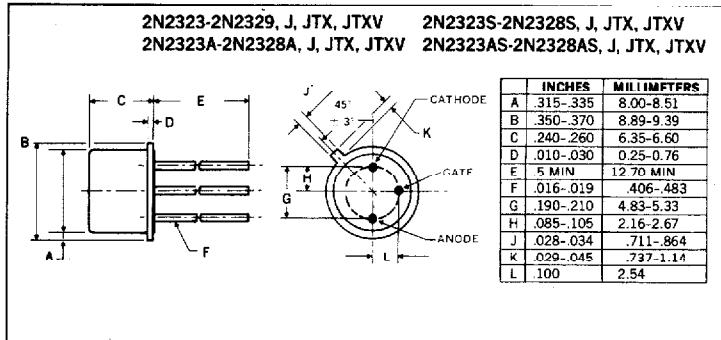
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2N2323	2N2324	2N2326	2N2328	2N2329
JAN2N2323S	JAN2N2324S	JAN2N2326S	JAN2N2328S	JAN2N2329S
JANTX2N2323S	JANTX2N2324S	JANTX2N2326S	JANTX2N2328S	JANTX2N2329S
JANTXV2N2323S	JANTXV2N2324S	JANTXV2N2326S	JANTXV2N2328S	JANTXV2N2329S
2N2323A	2N2324A	2N2325	2N2326A	2N2327
JAN2N2323AS	JAN2N2324AS	JAN2N2325A	JAN2N2326AS	JAN2N2327A
JANTX2N2323AS	JANTX2N2324AS	JANTX2N2325A	JANTX2N2326AS	JANTX2N2327A
JANTXV2N2323AS	JANTXV2N2324AS	JANTXV2N2325A	JANTXV2N2326AS	JANTXV2N2327A

ABSOLUTE MAXIMUM RATINGS

Repetitive Peak Off-State Voltage, V _{DRM}	50V	100V	150V	200V	250V	300V	400V
Repetitive Peak Reverse Voltage, V _{RDM}	50V	100V	150V	200V	250V	300V	400V
Non-Repetitive Peak Reverse Voltage, V _{RSM} (< 5ms)	75V	150V	225V	300V	350V	400V	500V
D.C. On-State Current, I _T							
80°C Ambient			300mA				
85°C Case			1.6A				
One Cycle Surge (Non-Rep.) On-State Current, I _{TSW}				15A			
Repetitive Peak On-State Current, I _{TM}				30A			
Gate Power Dissipation, P _{GM}				0.1W			
Gate Power Dissipation, P _{GM(AV)}				0.01W			
Peak Gate Current, I _{GM}			100mA				
Reverse Gate Voltage			6V				
Reverse Gate Current, I _{GR}			3mA				
Storage Temperature Range			-65°C to +150°C				
Operating Temperature Range			-65°C to +125°C				

MECHANICAL SPECIFICATIONS



TO-205AD (TO-39)



Microsemi Corp.
Watertown
 The diode experts

ELECTRICAL SPECIFICATIONS

 2N2323-2N2329, J, JTX, JTXV 2N2323S-2N2328S, J, JTX, JTXV
 2N2323A-2N2328A, J, JTX, JTXV 2N2323AS-2N2328AS, J, JTX, JTXV

Test	Symbol	Min.	Typical	Max.	Units	Test Conditions
Visual and Mechanical						MIL-STD-750, Method 2071
25°C						
Off-State Current	I_{DRM}	—	0.1	10	μA	$V_{DRM} = \text{Rating}$, $R_{GK} = 1K$ (2K for "A" Types)
Reverse Current	I_{RRM}	—	0.1	10	μA	$V_{RRM} = \text{Rating}$, $R_{GK} = 1K$ (2K for "A" Types)
Gate Trigger Current	I_{GT}	—	2	20	μA	$V_D = 6V$, $R_L = 100\Omega$
"A" Types		—	50	200	μA	$V_D = 6V$, $R_L = 100\Omega$
non-"A" Types		—	—	—	—	—
Gate Trigger Voltage	V_{GT}	0.35	0.52	0.60	V	$V_D = 6V$, $R_{GK} = 2K$, $R_L = 100\Omega$
"A" Types		0.35	0.55	0.80	V	$V_D = 6V$, $R_{GK} = 1K$, $R_L = 100\Omega$
non-"A" Types		—	—	—	—	—
On-State Voltage	V_{TM}	—	2.0	2.2	V	$I_{TM} = 4A$ (pulse test)
Holding Current	I_H	—	0.3	2.0	mA	$V_D = 6V$, $R_{GK} = 1K$ (2K for "A" Types)
Reverse Gate Current	I_{GR}	—	1	200*	μA	$V_{GR} = 6V$
Delay Time	t_d	—	0.6	—	μs	$I_G = 10mA$, $I_T = 1A$, $V_D = 30V$
Rise Time	t_r	—	0.4	—	μs	$I_G = 10mA$, $I_T = 1A$, $V_D = 30V$
Circuit Commutated Turn-Off Time	t_q	—	20	—	μs	$I_T = 1A$, $I_R = 1A$, $R_{GK} = 1K$
125°C						
Off-State Current	I_{DRM}	—	1	100	μA	$V_{DRM} = \text{Rating}$, $R_{GK} = 1K$ (2K for "A" Types)
Reverse Current	I_{RRM}	—	1	100	μA	$V_{RRM} = \text{Rating}$, $R_{GK} = 1K$ (2K for "A" Types)
Gate Trigger Voltage	V_{GT}	0.1	0.3	—	V	$V_D = \text{Rated } V_D$, $R_{GK} = 1K$ (2K for "A" Types)
Holding Current	I_H	—	—	—	—	—
"A" Types		0.1†	—	—	mA	$V_D = 6V$, $R_{GK} = 2K$
non-"A" Types		0.15†	—	—	mA	$V_D = 6V$, $R_{GK} = 1K$
Off-State Voltage — Critical Rate of Rise	dv/dt	—	—	—	V/ μs	$V_D = \text{Rating}$, $R_{GK} = 2K$
"A" Types		0.7*	—	—	V/ μs	$V_D = \text{Rating}$, $R_{GK} = 1K$
non-"A" Types		1.8*	—	—	V/ μs	—
-65°C						
Off-State Current	I_{DRM}	—	.05	5.0*	μA	$V_{DRM} = \text{Rating}$, $R_{GK} = 1K$ (2K for "A" Types)
Reverse Current	I_{RRM}	—	.05	5.0*	μA	$V_{RRM} = \text{Rating}$, $R_{GK} = 1K$ (2K for "A" Types)
Gate Trigger Current	I_{GT}	—	50	75	μA	$V_D = 6V$, $R_L = 100\Omega$
"A" Types		—	100	350	μA	$V_D = 6V$, $R_L = 100\Omega$
non-"A" Types		—	—	—	—	—
Gate Trigger Voltage	V_{GT}	—	0.7	0.8*	V	$V_D = 6V$, $R_{GK} = 2K$, $R_L = 100\Omega$
"A" Types		—	—	0.9†	V	$V_D = 6V$, $R_{GK} = 2K$, $R_L = 100\Omega$
non-"A" Types		—	0.75	1.0	V	$V_D = 6V$, $R_{GK} = 1K$, $R_L = 100\Omega$
Holding Current	I_H	—	—	3.0†	mA	$V_D = 6V$, $R_{GK} = 1K$ (2K for "A" Types)

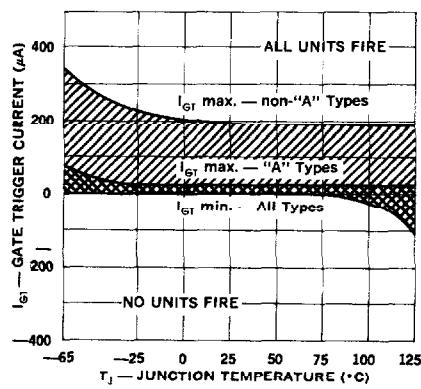
* JAN and JANTX Types only.

† Industrial Types only.

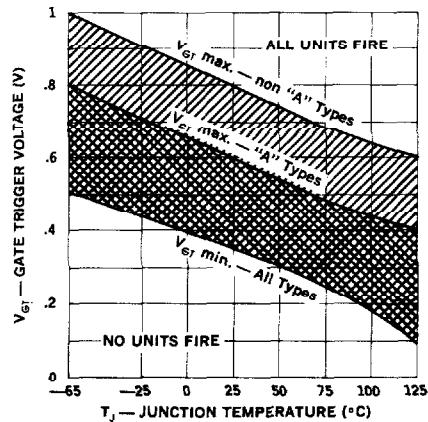
JAN and JANTX Acceptance Tests

100% Screening TX-Types	Group B Tests	Group C Tests
High Temperature Storage	Subgroup 1 — Reverse Gate Current	Subgroup 1 — Physical Dimensions
Temperature Cycling	Surge Current	Subgroup 2 — Shock
Constant Acceleration	Non-Repetitive Reverse Voltage	Constant Acceleration
Fine & Gross Hermetic Seal	Subgroup 2 — Low Temp. Reverse Blocking Current	Vibration, Variable Frequency
Electrical Test	Low Temp. Forward Blocking Current	Subgroup 3 — Barometric Pressure, Reduced
Burn-in	Low Temp. Gate Trigger Voltage	Subgroup 4 — Salt Atmosphere
Electrical Test	Low Temp. Gate Trigger Current	Subgroup 5 — Terminal Strength
	Subgroup 3 — Temperature Cycling	Subgroup 6 — Intermittent Operating Life Test
	Thermal Shock	
	Moisture Resistance	
	Solderability	
	Subgroup 4 — Blocking Life Test	

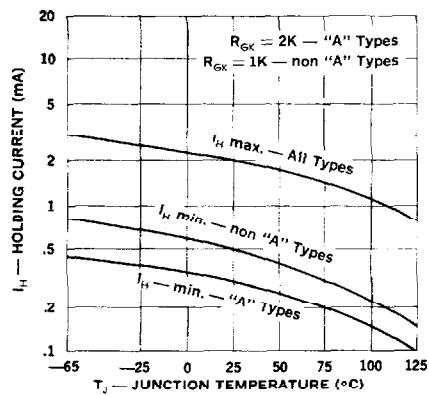
Gate Trigger Current



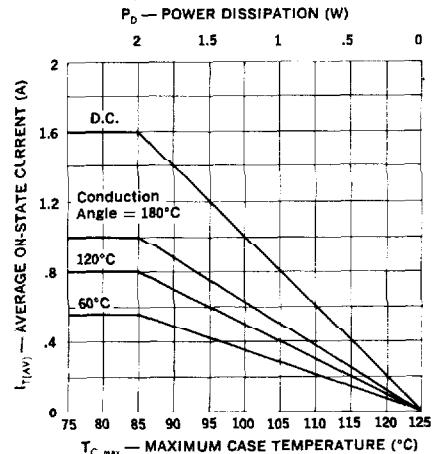
Gate Trigger Voltage



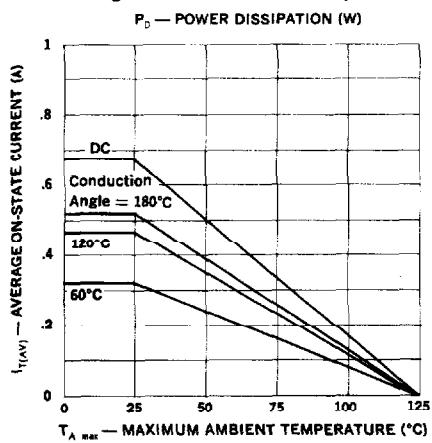
Holding Current



Average Current vs. Case Temperature



Average Current vs. Ambient Temperature



Surge Current

